LM117HVQML 3-Terminal Adjustable Regulator



Literature Number: SNVS357C



M117HVQML 3-Terminal Adjustable Regulator

LM117HVQML

3-Terminal Adjustable Regulator

General Description

The LM117HV are adjustable 3-terminal positive voltage regulators capable of supplying either 0.5A or 1.5A over a 1.2V to 57V output range. They are exceptionally easy to use and require only two external resistors to set the output voltage. Further, both line and load regulation are better than standard fixed regulators.

In addition to higher performance than fixed regulators, the LM117HV series offers full overload protection available only in IC's. Included on the chip are current limit, thermal overload protection and safe area protection. All overload protection circuitry remains fully functional even if the adjustment terminal is disconnected.

Normally, no capacitors are needed unless the device is situated more than 6 inches from the input filter capacitors in which case an input bypass is needed. An optional output capacitor can be added to improve transient response. The adjustment terminal can be bypassed to achieve very high ripple rejections ratios which are difficult to achieve with standard 3-terminal regulators.

Besides replacing fixed regulators, the LM117HV is useful in a wide variety of other applications. Since the regulator is "floating" and sees only the input-to-output differential voltage, supplies of several hundred volts can be regulated as long as the maximum input to output differential is not exceeded, i.e. do not short the output to ground.

Also, it makes an especially simple adjustable switching regulator, a programmable output regulator, or by connecting a fixed resistor between the adjustment and output, the LM117HV can be used as a precision current regulator. Supplies with electronic shutdown can be achieved by clamping the adjustment terminal to ground which programs the output to 1.2V where most loads draw little current.

Features

- Available with radiation guarantee

 Total lonizing Dose
 Low Dose Rate Qualified
 100 krad(Si)
 100 krad(Si)
- Adjustable output down to 1.2V
- Guaranteed 0.5A or 1.5A output current
- Line regulation typically 0.01%/V
- Load regulation typically 0.1%
- Current limit constant with temperature
 - Eliminates the need to stock many voltages
- 80 dB ripple rejection
- Output is short-circuit protected

Ordering Information

NS Part Number	SMD Part Number	NS Package Number	Package Description
LM117HVH/883		H03A	3LD T0–39 Metal Can
LM117HVH-QML	5962-0722901QXA	H03A	3LD T0–39 Metal Can
LM117HVHRQMLV (<i>Note 7</i>)	5962R0722901VXA 100 krad(Si)	H03A	3LD T0–39 Metal Can
LM117HVHRLQMLV (<i>Note 8</i>)	5962R0722961VXA	H03A	3LD T0–39 Metal Can
Low Dose Rate Qualified	100 krad(Si)		
LM117HVK/883		K02C	2LD T0–3 Low Profile Metal Can
LM117HVK-QML	5962-0722903QYA	K02C	2LD T0–3 Low Profile Metal Can
LM117HVWG-QML	5962-0722901QZA	WG16A	16LD Ceramic SOIC
LM117HVWGRQMLV(<i>Note 7</i>)	5962R0722901VZA	WG16A	16LD Ceramic SOIC
	100 krad(Si)		
LM117HVWGRLQMLV(<i>Note 8</i>)	5962R0722961VZA	WG16A	16LD Ceramic SOIC
Low Dose Rate Qualified	100 krad(Si)		
LM117HVGW-QML	5962-0722902QZA	WG16A	16LD Ceramic SOIC
LM117HVGWRQMLV (<i>Note 7</i>)	5962R0722902VZA	WG16A	16LD Ceramic SOIC
	100 krad(Si)		
LM117HVGWRLQMLV (Note 8)	5962R0722962VZA	WG16A	16LD Ceramic SOIC
Low Dose Rate Qualified	100 krad(Si)		

Connection Diagrams

(See Physical Dimension section for further information)





Absolute Maximum Ratings (Note 1)

Power Dissipation (<i>Note 2</i>) Input - Output Voltage Differential Maximum Junction Temperature Storage Temperature Lead Temperature (Soldering, 10 sec.)	Internally limited +60V, -0.3V +150°C -65°C $\leq T_A \leq$ +150°C 300°C
Thermal Resistance	
θιΑ	
T0-3 Metal Can - Still Air	39°C/W
T0-3 Metal Can - 500LF/Min Air flow	14°C/W
T0-39 Metal Can - Still Air	186°C/W
T0-39 Metal Can - 500LF/Min Air flow	64°C/W
Ceramic SOIC - Still Air "WG"	115°C/W
Ceramic SOIC - 500LF/Min Air flow "WG"	66°C/W
Ceramic SOIC - Still Air "GW"	130°C/W
Ceramic SOIC - 500LF/Min Air flow "GW"	80°C/W
θ _{JC}	
T0-3 Metal Can	1.9°C/W
T0-39 Metal Can	21°C/W
Ceramic SOIC "WG" (<i>Note 5</i>)	3.4°C/W
Ceramic SOIC "GW"	7°C/W
ESD Tolerance (<i>Note 3</i>)	2000V

Recommended Operating Conditions

Operating Temperature Range

 $-55^{\circ}C \le T_A \le +125^{\circ}C$

Quality Conformance Inspection

Subgroup	Description	Temp °C
1	Static tests at	25
2	Static tests at	125
3	Static tests at	-55
4	Dynamic tests at	25
5	Dynamic tests at	125
6	Dynamic tests at	-55
7	Functional tests at	25
8A	Functional tests at	125
8B	Functional tests at	-55
9	Switching tests at	25
10	Switching tests at	125
11	Switching tests at	-55
12	Settling time at	25
13	Settling time at	125
14	Settling time at	-55

LM117HVH, HVWG Electrical Characteristics

DC Parameters

The following conditions apply, unless otherwise specified. $V_{Diff} = (V_I - V_O)$, $I_L = 8mA$, $V_{OUT} = 1.25V$ (Nominal)

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub- groups
l _{Adj}	Adjustment Pin Current	V _{Diff} = 3V			100	μA	1
		$V_{\text{Diff}} = 3.3 \text{V}$			100	μA	2, 3
		$V_{\text{Diff}} = 40 \text{V}$			100	μA	1, 2, 3
IQ	Minimum Load Current	$V_{\text{Diff}} = 3V, V_{O} = 1.7V$			5.0	mA	1
		$V_{\text{Diff}} = 3.3 \text{V}, V_{\text{O}} = 1.7 \text{V}$			5.0	mA	2, 3
		V _I = 40V, V _O = 1.7V			5.0	mA	1, 2, 3
		$V_{I} = 60V, V_{O} = 1.7V$			8.2	mA	1
V _{Ref}	Reference Voltage	$V_{\text{Diff}} = 3V$		1.2	1.3	V	1
		$V_{\text{Diff}} = 3.3 V$		1.2	1.3	V	2, 3
		$V_{\text{Diff}} = 40 V$		1.2	1.3	V	1, 2, 3
V _{RLine}	Line Regulation	$3V \le V_{\text{Diff}} \le 40V,$ $V_{\text{O}} = V_{\text{Bef}}$		-8.64	8.64	mV	1
		$3.3V \le V_{\text{Diff}} \le 40V,$ $V_{O} = V_{\text{Ref}}$		-18	18	mV	2, 3
		$40V \le V_{\text{Diff}} \le 60V,$ $I_{\text{L}} = 60\text{mA}$		-25	25	mV	1
V _{RLoad}	Load Regulation	$V_{\text{Diff}} = 3V,$ $I_{\text{L}} = 10\text{mA}$ to 500mA		-15	15	mV	1
		$V_{\text{Diff}} = 3.3 \text{V},$ $I_{\text{L}} = 10 \text{mA to } 500 \text{mA}$		-15	15	mV	2, 3
		$V_{\text{Diff}} = 40V,$ $I_{\text{L}} = 10\text{mA} \text{ to } 150\text{mA}$		-15	15	mV	1
		$V_{\text{Diff}} = 40V,$ $I_{\text{L}} = 10\text{mA} \text{ to } 100\text{mA}$		-15	15	mV	2, 3
Delta I _{Adj} / Load	Adjustment Pin Current Change	$V_{\text{Diff}} = 3V,$ $I_{\text{L}} = 10\text{mA}$ to 500mA		-5.0	5.0	μA	1
		$V_{\text{Diff}} = 3.3 \text{V},$ $I_{\text{L}} = 10 \text{mA to } 500 \text{mA}$		-5.0	5.0	μA	2, 3
		$V_{\text{Diff}} = 40V,$ $I_{\text{L}} = 10\text{mA}$ to 150mA		-5.0	5.0	μA	1
		$V_{\text{Diff}} = 40V,$ $I_{\text{L}} = 10\text{mA}$ to 100mA		-5.0	5.0	μA	2, 3
Delta I _{Adj} /	Adjustment Pin Current Change	$3V \le V_{\text{Diff}} \le 40V$		-5.0	5.0	μA	1
Line		$3.3V \le V_{\text{Diff}} \le 40V$		-5.0	5.0	μA	2, 3
	Short Circuit Current	$V_{\text{Diff}} = 60 \text{V}$		0.0	0.4	A	1
		V _{Diff} = 4.25V		0.5	1.8	A	1
θ _R	Thermal Regulation	$V_{\text{Diff}} = 40V, I_{\text{L}} = 150\text{mA},$ t = 20mS			6.0	mV	1

AC Parameters

The following conditions apply, unless otherwise specified. $V_{Diff} = (V_1 - V_0)$, $I_L = 8mA$, $V_{OUT} = 1.25V$ (Nominal)

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub- groups
RR	Ripple Rejection	$V_1 = +6.25V, f = 120Hz,$	(Note 6)	66		dB	4, 5, 6
		$e_{I} = 1V_{RMS}, I_{L} = 125mA,$					
		$V_{O} = V_{Ref}$					

LM117HVH, HVWG Delta Electrical Characteristics

DC Delta Parameters

The following conditions apply, unless otherwise specified.

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub- groups
l _{Adj}	Adjust Pin Current	V _{Diff} = 3V		-10	10	μA	1
		$V_{\text{Diff}} = 40V$		-10	10	μA	1
V _{Ref}	Reference Voltage	V _{Diff} = 3V		-0.01	0.01	V	1
		$V_{\text{Diff}} = 40V$		-0.01	0.01	V	1
V _{RLine} Line Regul	Line Regulation	$3V \le V_{Diff} \le 40V,$ $V_O = V_{Ref}$		-4.0	4.0	mV	1
		$40V \le V_{\text{Diff}} \le 60V,$ I _L = 60mA		-6.0	6.0	mV	1

LM117HVH, HVWG Post Radiation Electrical Characteristics

DC Parameters

The following conditions apply, unless otherwise specified. $V_{Diff} = (V_1 - V_0)$, $I_L = 8mA$, $V_{OUT} = 1.25V$ (Nominal)

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub- groups
V _{Ref}	Reference Voltage	V _{Diff} = 3V		1.2	1.45	V	1
		$V_{\text{Diff}} = 40V$		1.2	1.45	V	1
V _{RLine}	Line Regulation	$3V \le V_{\text{Diff}} \le 40V,$		-40	40	mV	1
		$V_{O} = V_{Ref}$					
V _{RLoad}	Load Regulation	$V_{\text{Diff}} = 3V,$		-27	27	mV	1
		$I_{L} = 10 \text{mA}$ to 500 mA					

AC Parameters

The following conditions apply, unless otherwise specified. $V_{Diff} = (V_I - V_O)$, $I_L = 8mA$, $V_{OUT} = 1.25V$ (Nominal)

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub- groups
RR	Ripple Rejection	$V_{I} = +6.25V, f = 120Hz,$		55		dB	4
		$e_{I} = 1V_{RMS}, I_{L} = 125mA,$					
		$V_{O} = V_{Ref}$					

LM117HVK Electrical Characteristics

DC Parameters

The following conditions apply, unless otherwise specified. $V_{Diff} = (V_I - V_O)$, $I_L = 10mA$, $V_{OUT} = 1.25V$ (Nominal)

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub- groups
I _{Adj}	Adjustment Pin Current	V _{Diff} = 3V			100	μA	1
		V _{Diff} = 3.3V			100	μA	2, 3
		V _{Diff} = 40V			100	μA	1, 2, 3
l _Q	Minimum Load Current	$V_{\text{Diff}} = 3V, V_{\text{O}} = 1.7V$			5.0	mA	1
		$V_{\text{Diff}} = 3.3 \text{V}, V_{\text{O}} = 1.7 \text{V}$			5.0	mA	2, 3
		$V_1 = 40V, V_0 = 1.7V$			5.0	mA	1, 2, 3
		$V_{I} = 60V, V_{O} = 1.7V$		0.25	8.2	mA	1
V _{Ref}	Reference Voltage	$V_{\text{Diff}} = 3V$		1.2	1.3	V	1
		$V_{\text{Diff}} = 3.3 \text{V}$		1.2	1.3	V	2, 3
		$V_{\text{Diff}} = 40 V$		1.2	1.3	V	1, 2, 3
V _{RLine}	Line Regulation	$3V \le V_{\text{Diff}} \le 40V,$ $V_{O} = V_{\text{Bef}}$		-8.64	8.64	mV	1
		$3.3V \le V_{\text{Diff}} \le 40V,$ $V_{O} = V_{\text{Ref}}$		-18	18	mV	2, 3
		$40V \le V_{\text{Diff}} \le 60V,$ $I_{\text{L}} = 60\text{mA}$		-25	25	mV	1
V _{RLoad}	Load Regulation	$V_{\text{Diff}} = 3V,$ $I_{\text{L}} = 10\text{mA to } 1.5\text{A}$		-15	15	mV	1
		V _{Diff} = 3.3V, I _L = 10mA to 1.5A		-15	15	mV	2, 3
		$V_{\text{Diff}} = 40V,$ $I_{\text{L}} = 10\text{mA to }300\text{mA}$		-15	15	mV	1
		$V_{\text{Diff}} = 40V,$ $I_{\text{L}} = 10\text{mA to } 195\text{mA}$		-15	15	mV	2, 3
Delta I _{Adj} / Load	Adjustment Pin Current Change	$V_{\text{Diff}} = 3V,$ $I_{\text{L}} = 10\text{mA to } 1.5\text{A}$		-5.0	5.0	μA	1
		V _{Diff} = 3.3V, I _L = 10mA to 1.5A		-5.0	5.0	μΑ	2, 3
		$V_{\text{Diff}} = 40V,$ $I_{\text{L}} = 10\text{mA to }300\text{mA}$		-5.0	5.0	μA	1
		$V_{\text{Diff}} = 40V,$ $I_{\text{L}} = 10\text{mA}$ to 195mA		-5.0	5.0	μΑ	2, 3
Delta I _{Adj} /	Adjustment Pin Current Change	$3V \le V_{\text{Diff}} \le 40V$		-5.0	5.0	μA	1
Line		$3.3V \le V_{\text{Diff}} \le 40V$		-5.0	5.0	μA	2, 3
I _{os}	Short Circuit Current	$V_{\text{Diff}} = 60 \text{V}$		0.0	0.4	А	1
		V _{Diff} = 3V		1.5	3.5	А	1
θ _R	Thermal Regulation	$V_{\text{Diff}} = 40V, I_{\text{L}} = 300\text{mA},$ t = 20mS			10.5	mV	1

AC Parameters

The following conditions apply, unless otherwise specified. $V_{\text{Diff}} = (V_1 - V_0)$, $I_L = 10 \text{mA}$.

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub- groups
RR	Ripple Rejection	$V_1 = +6.25V, f = 120Hz,$	(Note 6)	66		dB	4, 5, 6
		$e_{I} = 1V_{RMS}, I_{L} = 0.5A,$					
		V _O = V _{Ref}					

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.

Note 2: The maximum power dissipation must be derated at elevated temperatures and is dictated by $T_{J_{max}}$ (maximum junction temperature), θ_{JA} (package junction to ambient thermal resistance), and T_A (ambient temperature). The maximum allowable power dissipation at any temperature is $P_{Dmax} = (T_{J_{max}} - T_A) / \theta_{JA}$ or the number given in the Absolute Maximum Ratings, whichever is lower. "Although power dissipation is internally limited, these specifications are applicable for power dissipations of 2W for the TO39 package and 20W for the TO3 package."

Note 3: Human body model, $1.5 \text{ k}\Omega$ in series with 100 pF.

Note 4: For the Ceramic SOIC device to function properly, the "Output" and "Output/Sense" pins must be connected on the users printed circuit board.

Note 5: The package material for these devices allows much improved heat transfer over our standard ceramic packages. In order to take full advantage of this improved heat transfer, heat sinking must be provided between the package base (directly beneath the die), and either metal traces on, or thermal vias through, the printed circuit board. Without this additional heat sinking, device power dissipation must be calculated using θ_{JA} , rather than θ_{JC} , thermal resistance. It must not be assumed that the device leads will provide substantial heat transfer out the package, since the thermal resistance of the lead frame material is very poor, relative to the material of the package base. The stated θ_{JC} thermal resistance is for the package material only, and does not account for the additional thermal resistance between the package, to calculate the total allowed power dissipation for the device.

Note 6: Tested @ 25°C; guaranteed, but not tested @ 125°C & -55°C

Note 7: Pre and post irradiation limits are identical to those listed under AC and DC electrical characteristics, except as listed in the "LM117HVH, HVWG Post Radiation Electrical Characteristics" tables . These parts may be dose rate sensitive in a space environment and demonstrate enhanced low dose rate effect. Radiation end point limits for the noted parameters are guaranteed only for the conditions as specified in Mil-Std-883, Method 1019, Condition A.

Note 8: Pre and post irradiation limits are identical to those listed under AC and DC electrical characteristics, except as listed in the "LM117HVH, HVWG Post Radiation Electrical Characteristics" tables. These parts pass all post irradiation limits under low dose rate testing at 10 mrad(Si)/s. Low dose rate qualification is performed on a wafer-by-wafer basis, per test method 1019 condition E of MIL-STD-883.

Typical Performance Characteristics Output capacitor = 0 µF unless otherwise noted.

LM117HVQML









20143843

Typical Radiation Characteristics (Note 9)









60

50∟ 0

20

40

DOSE (krad)

LOW DOSE RATE BIASED

80

100

20143851

LOW DOSE RATE UNBIASED

60

LM117HVQML

www.national.com

Application Hints

In operation, the LM117HV develops a nominal 1.25V reference voltage, V_{REF} , between the output and adjustment terminal. The reference voltage is impressed across program resistor R1 and, since the voltage is constant, a constant current I₁ then flows through the output set resistor R2, giving an output voltage of



FIGURE 1.

Since the 100 μA current from the adjustment terminal represents an error term, the LM117HV was designed to minimize I_{ADJ} and make it very constant with line and load changes. To do this, all quiescent operating current is returned to the output establishing a minimum load current requirement. If there is insufficient load on the output, the output will rise.

EXTERNAL CAPACITORS

An input bypass capacitor is recommended. A 0.1 μ F disc or 1 μ F solid tantalum on the input is suitable input bypassing for almost all applications. The device is more sensitive to the absence of input bypassing when adjustment or output capacitors are used but the above values will eliminate the possibility of problems.

The adjustment terminal can be bypassed to ground on the LM117HV to improve ripple rejection. This bypass capacitor prevents ripple from being amplified as the output voltage is increased. With a 10 μ F bypass capacitor 80 dB ripple rejection is obtainable at any output level. Increases over 10 μ F do not appreciably improve the ripple rejection at frequencies above 120 Hz. If the bypass capacitor is used, it is sometimes necessary to include protection diodes to prevent the capacitor from discharging through internal low current paths and damaging the device.

In general, the best type of capacitors to use are solid tantalum. Solid tantalum capacitors have low impedance even at high frequencies. Depending upon capacitor construction, it takes about 25 μF in aluminum electrolytic to equal 1 μF solid tantalum at high frequencies. Ceramic capacitors are also good at high frequencies; but some types have a large decrease in capacitance at frequencies around 0.5 MHz. For this reason, 0.01 μF disc may seem to work better than a 0.1 μF disc as a bypass.

Although the LM117HV is stable with no output capacitors, like any feedback circuit, certain values of external capaci-

tance can cause excessive ringing. This occurs with values between 500 pF and 5000 pF. A 1 μ F solid tantalum (or 25 μ F aluminum electrolytic) on the output swamps this effect and insures stability. Any increase of load capacitance larger than 10 μ F will merely improve the loop stability and output impedance.

LOAD REGULATION

The LM117HV is capable of providing extremely good load regulation but a few precautions are needed to obtain maximum performance. The current set resistor connected between the adjustment terminal and the output terminal (usually 240 Ω) should be tied directly to the output of the regulator rather than near the load. This eliminates line drops from appearing effectively in series with the reference and degrading regulation. For example, a 15V regulator with 0.05 Ω resistance between the regulator and load will have a load regulation due to line resistance of $0.05\Omega \times I_L$. If the set resistor is connected near the load the effective line resistance will be $0.05\Omega (1 + R2/R1)$ or in this case, 11.5 times worse.

Figure 2 shows the effect of resistance between the regulator and 240 Ω set resistor.



FIGURE 2. Regulator with Line Resistance in Output Lead

With the TO-3 package, it is easy to minimize the resistance from the case to the set resistor, by using two separate leads to the case. However, with the TO-5 package, care should be taken to minimize the wire length of the output lead. The ground of R2 can be returned near the ground of the load to provide remote ground sensing and improve load regulation.

PROTECTION DIODES

When external capacitors are used with *any* IC regulator it is sometimes necessary to add protection diodes to prevent the capacitors from discharging through low current points into the regulator. Most 10 μ F capacitors have low enough internal series resistance to deliver 20A spikes when shorted. Although the surge is short, there is enough energy to damage parts of the IC.

When an output capacitor is connected to a regulator and the input is shorted, the output capacitor will discharge into the output of the regulator. The discharge current depends on the value of the capacitor, the output voltage of the regulator, and the rate of decrease of V_{IN} . In the LM117HV, this discharge path is through a large junction that is able to sustain 15A surge with no problem. This is not true of other types of positive regulators. For output capacitors of 25 μ F or less, there is no need to use diodes.

The bypass capacitor on the adjustment terminal can discharge through a low current junction. Discharge occurs when either the input or output is shorted. Internal to the LM117HV is a 50Ω resistor which limits the peak discharge current. No protection is needed for output voltages of 25V or less and 10 μ F capacitance. Figure 3 shows an LM117HV with protection diodes included for use with outputs greater than 25V and high values of output capacitance.

CURRENT LIMIT

Internal current limit will be activated whenever the output current exceeds the limit indicated in the Typical Performance Characteristics. However, if during a short circuit condition the regulator's differential voltage exceeds the Absolute Maximum Rating of 60V (e.g. $V_{IN} \ge 60V$, $V_{OUT} = 0V$), internal junctions in the regulator may break down and the device may be damaged or fail. Failure modes range from an apparent open or short from input to output of the regulator, to a destroyed package (most common with the TO-220 package). To protect the regulator, the user is advised to be aware of voltages that may be applied to the regulator during fault conditions, and to avoid violating the Absolute Maximum Ratings.



FIGURE 3. Regulator with Protection Diodes

 $V_{OUT} = 1.25V \left(1 + \frac{R^2}{R^2}\right) + I_{ADJ}R^2$

Note: D1 protects against C1 D2 protects against C2

Typical Applications



Full output current not available at high input-output voltages

 \dagger Optional—improves transient response. Output capacitors in the range of 1 μ F to 1000 μ F of aluminum or tantalum electrolytic are commonly used to provide improved output impedance and rejection of transients.

*Needed if device is more than 6 inches from filter capacitors.

$$^{\dagger\dagger}V_{OUT} = 1.25V\left(1 + \frac{R2}{R1}\right) + I_{ADJ}R_2$$





*Sets maximum V_{OUT}



Adjustable Regulator with Improved Ripple Rejection LM117HV Vour VIN VIN ADJ D1* R1 C2 1N4002 240 0.1µF C3 $1\mu F^{\dagger}$ C1 R2 $10\mu F$ 5k

20143810

†Solid tantalum
*Discharges C1 if output is shorted to ground

LM117HVQML





20143813



Full output current not available at high input-output voltages







*Minimum load current \approx 4 mA









*Sets peak current (0.6A for 1 Ω) **The 1000 μ F is recommended to filter out input transients

20143827

Date Released	Revision	Section	Originator	Changes
03/14/06	A	New Release, Corporate format	L. Lytle	2 MDS datasheets converted into one Corporate datasheet format. Corrected I_L from 60mA to 8mA for R_{Line} . Separated Delta I_{Adj} / Line from Delta I_{Adj} / Load for both the H & K devices. Removed drift from MNLM117HV-H electrical characteristics since not performed on 883 product. MNLM117HV-K Rev 0C1 & MNLM117HV-H Rev 2A1 will be archived.
07/06/07	В	Features, Ordering Information, Connection Diagram, Absolute Maximum Ratings, Electrical's, Notes and Physical Dimensions	Larry McGee	Added Radiation information and WG information to data sheet. Revision A to be Archived.
02/13/08	С	Features, Ordering Information, Electrical's, Notes and Typical Radiation Characteristics, Physical Dimensions Drawing	Larry McGee	Added ELDRS NSID information, HVH & HVWG Delta and Post Radiation Table, Typical Radiation Characteristics Plots, Note 8, 9 and WG Market Drawing. Revision B to be Archived.
09/02/11	D	Ordering Information, Absolute Maximum Ratings	Larry McGee	Added 'GW' NSIDS & SMD numbers. Added Theta JA and Theta JC for 'GW' devices. Revision C to be Archived.







Notes

For more National Semiconductor product information and proven design tools, visit the following Web sites at: www.national.com

Pr	oducts	Desig	n Support
Amplifiers	www.national.com/amplifiers	WEBENCH® Tools	www.national.com/webench
Audio	www.national.com/audio	App Notes	www.national.com/appnotes
Clock and Timing	www.national.com/timing	Reference Designs	www.national.com/refdesigns
Data Converters	www.national.com/adc	Samples	www.national.com/samples
Interface	www.national.com/interface	Eval Boards	www.national.com/evalboards
LVDS	www.national.com/lvds	Packaging	www.national.com/packaging
Power Management	www.national.com/power	Green Compliance	www.national.com/quality/green
Switching Regulators	www.national.com/switchers	Distributors	www.national.com/contacts
LDOs	www.national.com/ldo	Quality and Reliability	www.national.com/quality
LED Lighting	www.national.com/led	Feedback/Support	www.national.com/feedback
Voltage References	www.national.com/vref	Design Made Easy	www.national.com/easy
PowerWise® Solutions	www.national.com/powerwise	Applications & Markets	www.national.com/solutions
Serial Digital Interface (SDI)	www.national.com/sdi	Mil/Aero	www.national.com/milaero
Temperature Sensors	www.national.com/tempsensors	SolarMagic™	www.national.com/solarmagic
PLL/VCO	www.national.com/wireless	PowerWise® Design University	www.national.com/training

THE CONTENTS OF THIS DOCUMENT ARE PROVIDED IN CONNECTION WITH NATIONAL SEMICONDUCTOR CORPORATION ("NATIONAL") PRODUCTS. NATIONAL MAKES NO REPRESENTATIONS OR WARRANTIES WITH RESPECT TO THE ACCURACY OR COMPLETENESS OF THE CONTENTS OF THIS PUBLICATION AND RESERVES THE RIGHT TO MAKE CHANGES TO SPECIFICATIONS AND PRODUCT DESCRIPTIONS AT ANY TIME WITHOUT NOTICE. NO LICENSE, WHETHER EXPRESS, IMPLIED, ARISING BY ESTOPPEL OR OTHERWISE, TO ANY INTELLECTUAL PROPERTY RIGHTS IS GRANTED BY THIS DOCUMENT.

TESTING AND OTHER QUALITY CONTROLS ARE USED TO THE EXTENT NATIONAL DEEMS NECESSARY TO SUPPORT NATIONAL'S PRODUCT WARRANTY. EXCEPT WHERE MANDATED BY GOVERNMENT REQUIREMENTS, TESTING OF ALL PARAMETERS OF EACH PRODUCT IS NOT NECESSARILY PERFORMED. NATIONAL ASSUMES NO LIABILITY FOR APPLICATIONS ASSISTANCE OR BUYER PRODUCT DESIGN. BUYERS ARE RESPONSIBLE FOR THEIR PRODUCTS AND APPLICATIONS USING NATIONAL COMPONENTS. PRIOR TO USING OR DISTRIBUTING ANY PRODUCTS THAT INCLUDE NATIONAL COMPONENTS, BUYERS SHOULD PROVIDE ADEQUATE DESIGN, TESTING AND OPERATING SAFEGUARDS.

EXCEPT AS PROVIDED IN NATIONAL'S TERMS AND CONDITIONS OF SALE FOR SUCH PRODUCTS, NATIONAL ASSUMES NO LIABILITY WHATSOEVER, AND NATIONAL DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY RELATING TO THE SALE AND/OR USE OF NATIONAL PRODUCTS INCLUDING LIABILITY OR WARRANTIES RELATING TO FITNESS FOR A PARTICULAR PURPOSE, MERCHANTABILITY, OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

LIFE SUPPORT POLICY

NATIONAL'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS PRIOR WRITTEN APPROVAL OF THE CHIEF EXECUTIVE OFFICER AND GENERAL COUNSEL OF NATIONAL SEMICONDUCTOR CORPORATION. As used herein:

Life support devices or systems are devices which (a) are intended for surgical implant into the body, or (b) support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in a significant injury to the user. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system or to affect its safety or effectiveness.

National Semiconductor and the National Semiconductor logo are registered trademarks of National Semiconductor Corporation. All other brand or product names may be trademarks or registered trademarks of their respective holders.

Copyright© 2011 National Semiconductor Corporation

For the most current product information visit us at www.national.com



National Semiconductor Americas Technical Support Center Email: support@nsc.com Tel: 1-800-272-9959

National Semiconductor Europe Technical Support Center Email: europe.support@nsc.com National Semiconductor Asia Pacific Technical Support Center Email: ap.support@nsc.com National Semiconductor Japan Technical Support Center Email: jpn.feedback@nsc.com

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, modifications, enhancements, improvements, and other changes to its products and services at any time and to discontinue any product or service without notice. Customers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All products are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its hardware products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by government requirements, testing of all parameters of each product is not necessarily performed.

TI assumes no liability for applications assistance or customer product design. Customers are responsible for their products and applications using TI components. To minimize the risks associated with customer products and applications, customers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any TI patent right, copyright, mask work right, or other TI intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information published by TI regarding third-party products or services does not constitute a license from TI to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. Reproduction of this information with alteration is an unfair and deceptive business practice. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

TI products are not authorized for use in safety-critical applications (such as life support) where a failure of the TI product would reasonably be expected to cause severe personal injury or death, unless officers of the parties have executed an agreement specifically governing such use. Buyers represent that they have all necessary expertise in the safety and regulatory ramifications of their applications, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of TI products in such safety-critical applications, notwithstanding any applications-related information or support that may be provided by TI. Further, Buyers must fully indemnify TI and its representatives against any damages arising out of the use of TI products in such safety-critical applications.

TI products are neither designed nor intended for use in military/aerospace applications or environments unless the TI products are specifically designated by TI as military-grade or "enhanced plastic." Only products designated by TI as military-grade meet military specifications. Buyers acknowledge and agree that any such use of TI products which TI has not designated as military-grade is solely at the Buyer's risk, and that they are solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI products are neither designed nor intended for use in automotive applications or environments unless the specific TI products are designated by TI as compliant with ISO/TS 16949 requirements. Buyers acknowledge and agree that, if they use any non-designated products in automotive applications, TI will not be responsible for any failure to meet such requirements.

Following are URLs where you can obtain information on other Texas Instruments products and application solutions:

Products		Applications	
Audio	www.ti.com/audio	Communications and Telecom	www.ti.com/communications
Amplifiers	amplifier.ti.com	Computers and Peripherals	www.ti.com/computers
Data Converters	dataconverter.ti.com	Consumer Electronics	www.ti.com/consumer-apps
DLP® Products	www.dlp.com	Energy and Lighting	www.ti.com/energy
DSP	dsp.ti.com	Industrial	www.ti.com/industrial
Clocks and Timers	www.ti.com/clocks	Medical	www.ti.com/medical
Interface	interface.ti.com	Security	www.ti.com/security
Logic	logic.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Power Mgmt	power.ti.com	Transportation and Automotive	www.ti.com/automotive
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com		
OMAP Mobile Processors	www.ti.com/omap		
Wireless Connectivity	www.ti.com/wirelessconnectivity		

TI E2E Community Home Page

e2e.ti.com

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2011, Texas Instruments Incorporated